








 	<h2 style="color: red;">RFD3055LESM9A</h2> <p>Hersteller-Teilenummer: RFD3055LESM9A</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 11A TO-252AA</p> <p>Datenblätter:  RFD3055LESM9A.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 187710 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	RFD3055LESM9A
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 60V 11A TO-252AA
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	187710 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252AA
Verlustleistung (max)	38W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	11A (Tc)
Rds On (Max) @ Id, Vgs	107 mOhm @ 8A, 5V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	11.3nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	350pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V
Vgs (Max)	±16V
Verpackung	Tape & Reel (TR)



















































RFD3055LESM9A ist neu im Original, Suche RFD3055LESM9A Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RFD3055LESM9A Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage RFD3055LESM9A: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>RFD3055LESM9A AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 11A TO-252AA</p>	 <p>RFD3055LE AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 11A I-PAK</p>	 <p>RFD3055LE Fairchild/ON Semiconductor MOSFET N-CH 60V 11A I-PAK</p>	 <p>RFD3055SM AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 12A DPAK</p>
 <p>RFD3055RLESM96 FAIRCHILD RFD3055RLESM96 FAIRCHILD</p>	 <p>RFD3055LESM Fairchild/ON Semiconductor MOSFET N-CH 60V 11A TO-252AA</p>	 <p>RFD3055RLESM9A Original RFD3055RLESM9A Original</p>	 <p>RFD3055LESM9AS2568 FAIRCHILD RFD3055LESM9AS2568 FAIRCHILD</p>

heiße Teile

Mehr

 RFD16N05L	 RFD16N05LSM	 RFD16N05LSM	 RFD16N05LSM-NL	 RFD16N05LSM96S5000
 RFD16N05LSM9A	 RFD16N05LSM9A	 RFD16N05SM	 RFD16N05SM	 RFD16N05SM9A
 RFD16N05SM9A	 RFD16N06	 RFD16N06L	 RFD16N06LESM	 RFD16N06LESM9A
 RFD16N06LESM9A	 RFD16N06SM9A	 RFD20N03SM	 RFD20N03SM9A	 RFD3055L
 RFD3055LE	 RFD3055LE	 RFD3055LESM	 RFD3055LESM	 RFD3055LESM9A
 RFD3055LESM9AS2568	 RFD3055RLESM96	 RFD3055RLESM9A	 RFD3055SM	 RFD3055SM
 RFD3055SM9A	 RFD3055SM9A	 RFD4N06LSM	 RFD8P05SM	 RFD8P05SM
 RFD8P05SM9A	 RFD8P06ESM	 RFD8P06ESM9A	 RFD8P06LESM	 RFD8P06LESM9AR4407
 RFD8P06SM	 RFD8P06TM	 RFDA2026	 RFDA2026TR13	 RFDIP1608060T1T
 RFDIP1608060TM7T62	 RFDIP1608060TM8T62	 RFDIP160806ALM2T66	 RFDIP160806BLM5T62	 RFDIP160806BLM6T25

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